


Influence of preparation conditions on structural and dielectric properties of PVDF–MoS₂ nanotubes composite films

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Abstract Poly(vinylidene fluoride) composite films with MoS₂ nanotubes were prepared from solutions using the doctor blade method and dried under various temperatures. While FTIR-ATR and Raman spectroscopy have revealed that composite films dried at room temperature are homogeneous and crystallize mainly in the γ -phase, a decrease in porosity upon addition of MoS₂ has been observed using scanning electron microscopy. Dielectric investigations revealed (i) a decrease from $\varepsilon' \sim 7$ in pure polymer to $\varepsilon' \sim 4$ in composite with 1 wt% of MoS₂, and (ii) a slight increase in ε' and σ' values upon further addition of MoS₂. Films dried at 110 °C were heterogeneous and FTIR-ATR has shown an increase in α -phase content upon addition of 1 wt% of MoS₂. In this case, high values of $\varepsilon' \sim 10$ that increased slightly upon increasing amount of MoS₂ in the film have been measured. By showing a direct relation between structure and dielectric response, it is suggested that the dielectric properties of poly(vinylidene fluoride)–MoS₂ nanotubes composites can be tailored by changing the preparation conditions.

Keywords PVDF · MoS₂ nanotubes · Composites · Dielectric response · Raman spectroscopy · FTIR-ATR

Introduction

Poly(vinylidene fluoride) (PVDF) is a semicrystalline polymer, which has been attracting considerable attention due to its ferroelectric, piezoelectric, and pyroelectric properties, high elasticity and high dielectric constant values [1–3]. Its diverse morphology, obtained through easily controlled processing conditions, make it compelling for use in a vast array of applications in the areas of biomedicine, energy generation and storage, filtration, sensors and actuators [1, 3–6]. In PVDF, the molecular formula of which is (CH₂ – CF₂)_n, the dipole moment attached to the main chain can adopt various orientations depending on the conformation of the chain. The variety of ways in which the chains can pack into crystalline structures results in several polymorphous modifications, i.e., the diversity of PVDF arises partly due to its polymorphism, enabling crystallization into at least five phases (commonly known as the α , β , γ , δ and ε - phases) [1, 4, 7–9]. The non-polar α -phase is the most common, and is usually obtained by melt crystallization at temperatures below 160 °C. At higher temperatures a co-existence of the non-polar α and polar γ -phase occurs (the γ -phase occurrence increases with crystallization temperature and time) [1, 3, 8]. The most polar PVDF phase, the β -phase, can be obtained either from α -phase films by mechanical deformation or electrical poling [1, 3] or from the melt using high pressures [10] or epitaxial techniques [11]. Nonetheless, these methods often induce undesirable structural deformations or microstructural limitations which may hinder specific applications as electro-optical sensors and non-volatile memories [12, 13], for example. Concomitantly, alternative methods have been developed, i.e., the β -phase of PVDF has been obtained by doping the polymer with fillers such as BaTiO₃ [14], clays [15, 16], hydrated ionic salts [17], TiO₂ [18], ferrite nanoparticles [18] or multi-walled carbon nanotubes [19].

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Molybdenum disulfide nanotubes (MoS_2 NTs) are widely known for their use as a lubricant [20] and recent studies have shown that they are also potentially useful in other applications, such as hydrogen storage [21–23], catalysis [24], and sensor technologies [25]. Co-axial MoS_2 NTs with split walls have an exfoliated structure and have possible applications in polymer composites such as self-lubricating and anti-corrosive coatings or in solar cell applications [9]. Although the structural and dielectric properties of various systems composed of nanofillers within a polymer matrix were studied and characterized extensively over the last decade [3, 19, 26, 27], very little research and development has been performed on polymer nanocomposites using MoS_2 NTs as nanofillers [9]. In order to further develop our knowledge of polymer composites with MoS_2 NTs, we have investigated the influence of preparation conditions on the structural and dielectric properties of PVDF- MoS_2 NTs composite films using Fourier transform infrared spectroscopy (FTIR), Raman spectroscopy, and high-resolution dielectric spectroscopy across broad frequency and temperature ranges.

Materials and methods

PVDF- MoS_2 nanotubes (NTs) composite films were prepared from 20 wt% solutions of PVDF (301-F grade, Arkema) in dimethylformamide (DMF, Sigma Aldrich, $\geq 99\%$) and 0 wt% (pure PVDF), 1 wt%, and 2 wt% MoS_2 nanotubes (Nanotul Ltd. Ljubljana, Slovenia) with respect to the PVDF [9]. The solutions were air-cast on a glass plate and drawn by doctor blade (thickness of 300 μm) on a film applicator (Erichsen). Films were then dried for 24 h at 50 % relative humidity at 22 $^\circ\text{C}$ and removed from the glass plate after the drying process was completed. A second set of films was dried at 110 $^\circ\text{C}$. In the remaining text, the samples dried at 22 $^\circ\text{C}$ or 110 $^\circ\text{C}$ will be referred to as the room temperature (RT) or high temperature (HT) samples, respectively. The thickness of the films was 60 μm to 75 μm (RT samples) and 21 μm to

Table 1 Distinctive vibrational modes for different PVDF conformations in cm^{-1} units [28–31]

IR active			Raman active		
α	β	γ	α	β	γ
764		776			
796		812	795		812 w
855	840	833, 838		839 vs	839 s
976	884	883			
1149	1179	1117			
1210	1279	1234			
1383					

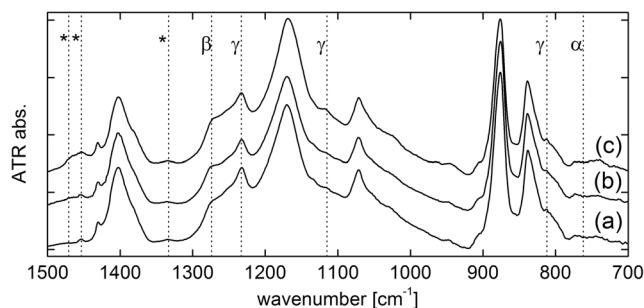


Fig. 1 FTIR-ATR spectra of RT PVDF (a), RT PVDF-1 wt% MoS_2 (b) and RT PVDF-2 wt% MoS_2 (c) films. All spectra are very similar and only γ -phase distinctive band at 1234 cm^{-1} can be observed

24 μm (HT samples). Their morphology was studied with field emission scanning electron microscope (SEM), Supra 36 VP, Carl Zeiss.

Fourier-transform infrared spectra (FTIR) in the mid-infrared region were measured by Perkin Elmer Spectrum 400 equipped with a Pike's GladiATR accessory and were recorded with 2 cm^{-1} resolution. For comparison, all spectra were normalized to a unit area since the porosity of the films, and consequently the overall intensity of the FTIR-ATR signal, was influenced by the addition of MoS_2 NTs.

Raman spectra were recorded with confocal Raman imaging system alpha300R (WITec) with a frequency doubled Nd:YAG laser (532 nm) in backscattering geometry. A full laser power of approximately 40 mW was used for the non-sensitive films (pure PVDF) and a reduced power of 6 mW was used for the sensitive samples (composites). A spectrometer with a grating of 1800 lines/mm was used. The acquisition time for a single spectrum was 5 to 10 min. In order to get sufficient sampling,

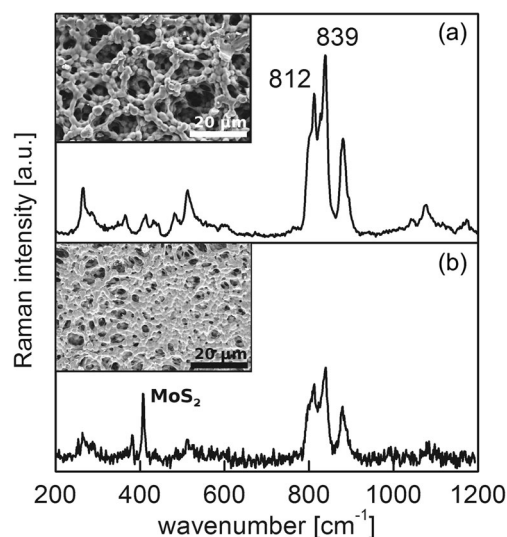
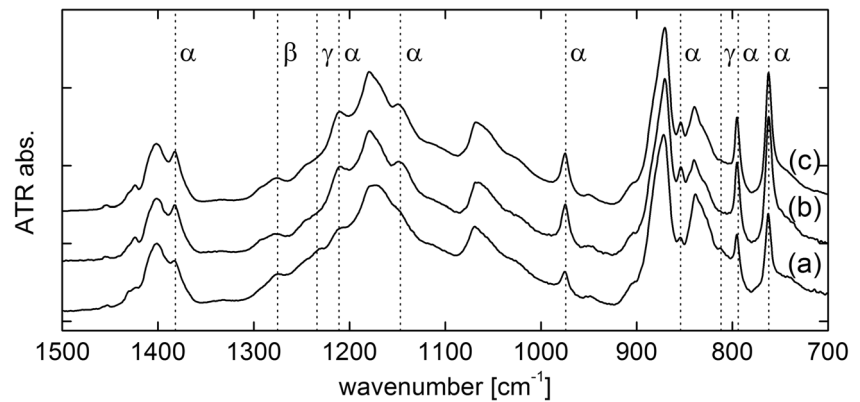


Fig. 2 Raman spectra of RT pure PVDF (a) and RT PVDF-1 wt% MoS_2 films (b). The γ -phase distinctive band at 812 cm^{-1} is clearly visible. Spectrum (b) is very similar to spectrum (a), with addition of 382 cm^{-1} and 408 cm^{-1} MoS_2 bands. Insets show SEM images of corresponding films' top surface. Porosity of RT PVDF-1 wt% MoS_2 film is decreased compared to pure PVDF RT film

Fig. 3 FTIR-ATR spectra of HT PVDF (a), HT PVDF-1 wt% MoS₂ (b) and HT PVDF-2 wt% MoS₂ (c) films at their *top side*



several single point spectra measurements on each sample were performed.

For dielectric measurements, films were covered with sputtered electrodes (100 nm of gold on 10 nm of chromium for better adhesion). The complex dielectric constant $\varepsilon^*(\Omega, T) = \varepsilon' - i\varepsilon''$ was measured with an HP4284A Precision LCR Meter using the amplitude of the probing AC electric signal of 1 V. The real part of the complex ac conductivity $\sigma^* = \sigma' + i\sigma''$ was calculated via $\sigma' = 2\pi\nu\varepsilon'\varepsilon''$, with ε' being the permittivity of free space. After heating the samples to 350 K, the dielectric response was detected during cooling runs at a rate of 0.9 Kmin⁻¹. The temperature of the samples was stabilized within ± 0.01 K by using a lock-in bridge technique with a platinum resistor Pt100 as a thermometer.

Results and discussion

Vibrational spectroscopy

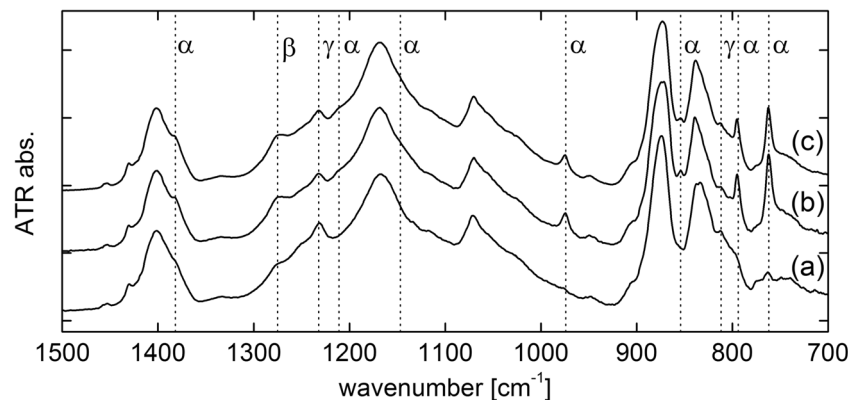
Numerous reports in the literature distinguish different PVDF phases on the basis of characteristic vibrational modes [28–31]. Vibrational spectroscopy gives direct information on the conformation of the chains, however, it does not provide information on the packing of the chains into crystals, which becomes relevant in the case of δ - and α -phase, which

have the same conformations but different crystalline structures [32]. Nonetheless, the standard nomenclature for conformations is used in this work, i.e. α -phase is used to denote the TGTG' conformation, β for TTTT and γ for TTTGTTTG'. Both infrared (IR) active and Raman active modes distinctive for these phases are summarized in Table 1. The α -phase has many distinctive bands in the mid-IR (764 cm⁻¹, 796 cm⁻¹, 976 cm⁻¹) and in Raman spectra (795 cm⁻¹). The γ -phase has one distinctive Raman active band (812 cm⁻¹) and β -phase has one distinctive IR active band (1279 cm⁻¹). Therefore, only with a combination of both vibrational techniques can we clearly distinguish the β - and γ -phases.

There is another advantage to using both techniques: the probed area using FTIR-ATR is 1 mm² whereas the probed area for confocal Raman spectroscopy is less than 1 μm^2 . FTIR-ATR thus provides averaged information over larger scales, while Raman spectroscopy provides local information and is suitable for checking homogeneity of the samples.

FTIR-ATR spectra of RT PVDF–MoS₂ films are presented in Fig. 1. Since MoS₂ has no characteristic bands in the mid-IR part [33] the absorption is related to PVDF only. The pure PVDF (a) and composites with MoS₂ added in the range of 1–2 wt% (b,c) all have very similar spectra. The γ -phase distinctive band at 1234 cm⁻¹ is clearly observed, while the β -phase distinctive band at 1279 cm⁻¹ appears as a shoulder. There is no α -phase distinctive band, and we can thus conclude that (i)

Fig. 4 FTIR-ATR spectra of HT PVDF (a), HT PVDF-1 wt% MoS₂ (b) and HT PVDF-2 wt% MoS₂ (c) films at their *bottom side*



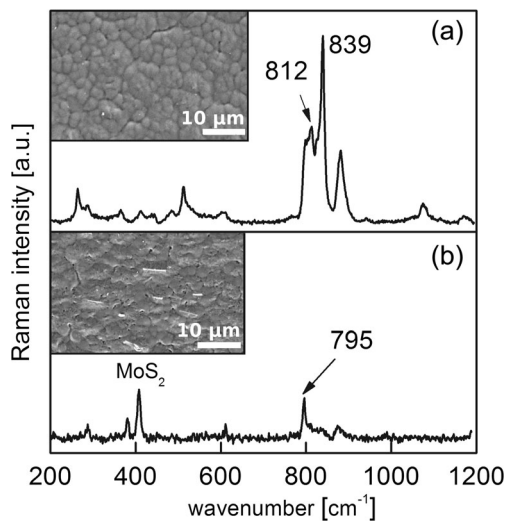


Fig. 5 Raman spectrum of HT pure PVDF film in β -phase rich point (a) with inset showing SEM of top surface of the film. Raman spectrum of PVDF-1 wt% MoS₂ (b) is dominated by α -phase. In the SEM image (inset) we can see MoS₂ NTs inside films

films prepared at room temperature mainly obtain the γ -phase conformation and (ii) the addition of MoS₂ NTs does not influence the conformation of PVDF chains. Although the peaks, marked with an asterisk in Fig. 1, cannot be explained by any of the possible conformations or crystalline structures of PVDF, the 1454 cm⁻¹ band, which is especially evident in the case of pure PVDF and less evident 1330 cm⁻¹ band can be attributed to irregular head-to-head and tail-to-tail linkages [31].

The Raman spectra of RT pure PVDF film (Fig. 2a) are in accordance with the γ -phase in the majority of randomly selected points on the sample. There is no trace of α -phase bands, however the presence of β -phase cannot be excluded solely on the basis of the Raman spectra data, as explained above. Typical single point spectra of RT PVDF-1 wt% MoS₂

(Fig. 2b) and PVDF-2 wt% MoS₂ films are very similar to the spectrum of RT pure PVDF. This is in agreement with the FTIR-ATR data which show that MoS₂ NTs do not change the phase of RT PVDF films (see Fig. 1). The Raman spectra of RT PVDF-MoS₂ films reveal intense 382 cm⁻¹ and 408 cm⁻¹ bands that belong to MoS₂ [33]. We also observe that PVDF-MoS₂ composite films are less stable upon laser illumination in comparison to pure films. Under high power illumination, spectra are either transformed or decomposition of the sample takes place. This sensitivity can be explained by the high light absorption coefficient of MoS₂ [34] and consequent heating of the polymer in the vicinity of NTs.

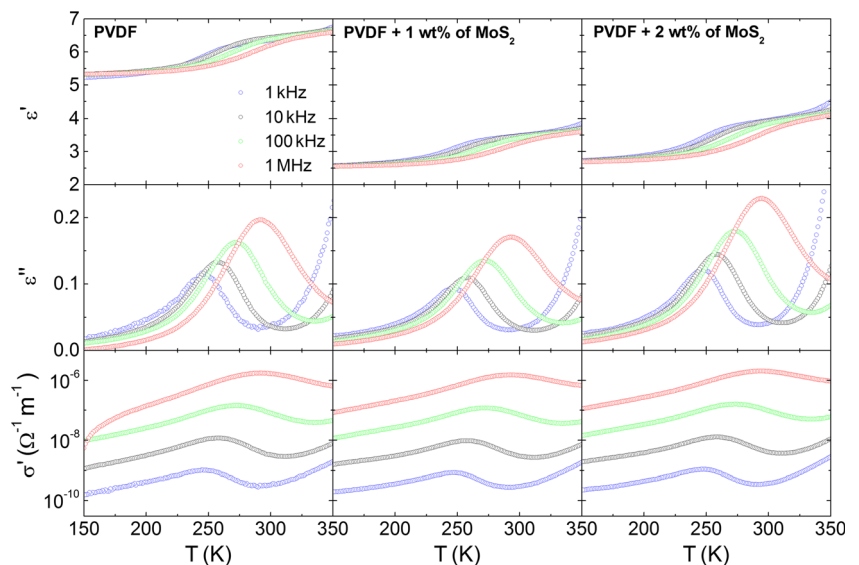
SEM micrographs of top surfaces of RT films are shown in the insets to Fig. 2. The RT pure PVDF film is porous, which is typical when drop casting PVDF solution at low temperature [8]. Porosity is greatly reduced with the addition of MoS₂ NTs.

Although the ATR spectra of HT PVDF-MoS₂ on the top (Fig. 3) and bottom (Fig. 4) surface vary slightly, it can be seen that MoS₂ NTs influence the crystallization of films dried at 110 °C. Upon addition of MoS₂ NTs the α -phase bands become more noticeable.

While the top surface spectra reveal a very weak β -phase band and practically no γ -phase band, the bottom surface has a less uniform structure in which all spectra have notable β and γ contributions. In both cases intensity of the α bands is increased upon addition of MoS₂ NTs. There is no notable difference between the spectra of PVDF-2 wt% MoS₂ NTs film and the spectra of PVDF-1 wt% MoS₂.

The Raman spectra of HT pure PVDF sample at different random points vary between phases, e.g., some points are rich in β and γ -phase (Fig. 5a), while other are rich in α -phase. In HT PVDF-MoS₂ films, spectra in the majority of points show α -phase (Fig. 5b). These results are consistent with FTIR-ATR results.

Fig. 6 The real, ϵ' , and the imaginary, ϵ'' , parts of the complex dielectric constant and the real, σ' , part of the complex ac conductivity vs. temperature, obtained at various frequencies in RT pure PVDF and PVDF-MoS₂ films



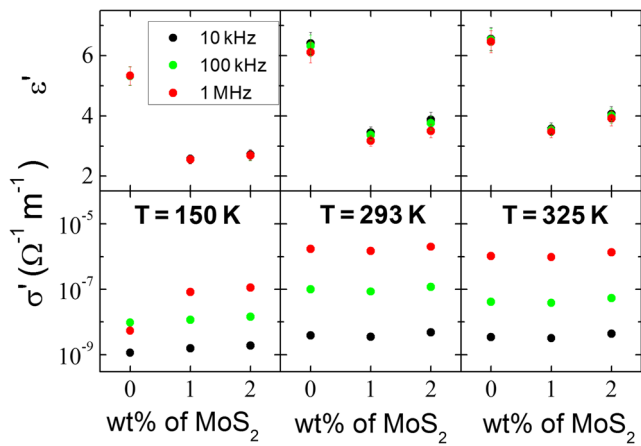


Fig. 7 ϵ' and σ' vs. wt% of MoS₂, detected at 150 K, 293 K, and 325 K in RT PVDF–MoS₂ films

The morphology of the HT pure PVDF and HT PVDF–1 wt% MoS₂ films are shown in the insets to Figs. 5a and 5b, respectively. The spherulites are completely interconnected and the surface is clearly not porous. The addition of MoS₂ nanotubes does not change the morphology.

Dielectric response

Dielectric spectroscopy is a powerful tool for the research and development of novel dielectric materials (e.g. PVDF-based polymers [35]) as it enables us to understand the behavior of interfaces at the boundary of two different materials or material phases and accurately control material properties.

Figure 6 shows a comparison of the temperature-dependent dielectric response of RT pure PVDF and PVDF–MoS₂ films. The dielectric relaxation, which can clearly be seen in the temperature interval of 200 K to 300 K is known to be a dynamic manifestation of the glass-to-rubber transition that takes place in the amorphous part of PVDF [36, 37]. The

Fig. 8 ϵ' , ϵ'' , and σ' vs. temperature, obtained at various frequencies in HT PVDF–MoS₂ films

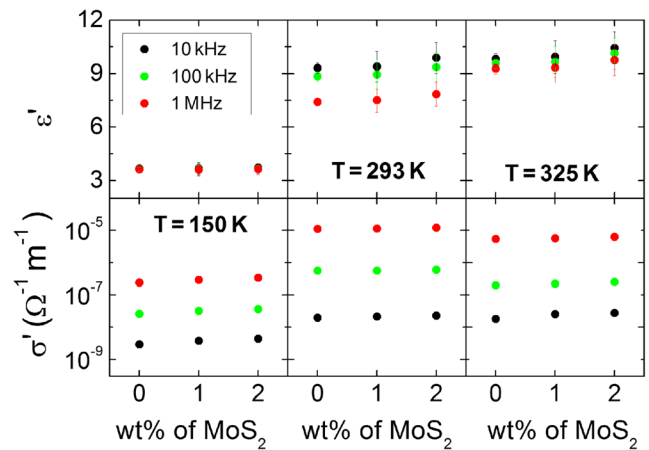
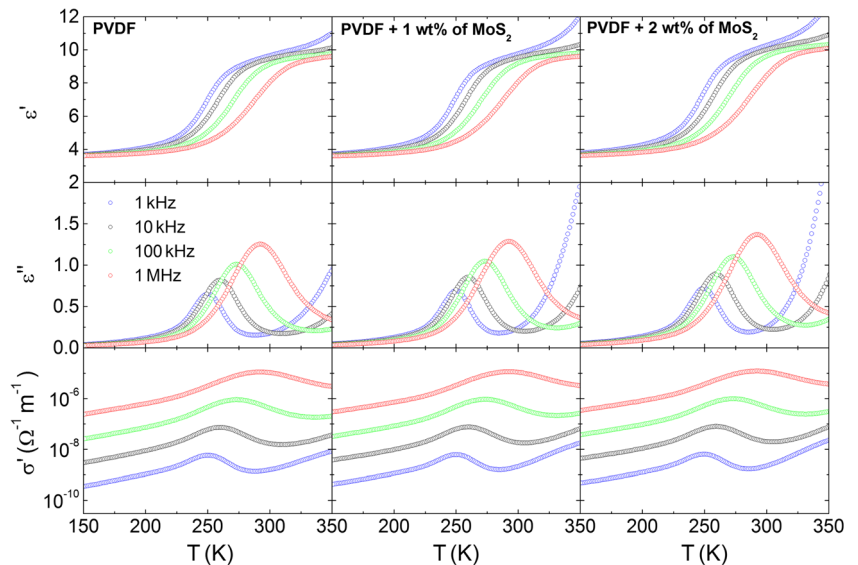


Fig. 9 ϵ' and σ' vs. wt% of MoS₂ nanotubes, detected at 150 K, 293 K, and 325 K in PVDF–MoS₂ films, prepared at 393 K

addition of 1 wt% of MoS₂ nanotubes strongly decreases the values of the real part of the complex dielectric constant, ϵ' , while the values of the imaginary part, ϵ'' (which represent the dielectric losses, i.e., the electrical conductivity of the system), remain almost unchanged, and the characteristic dynamic peaks in $\epsilon''(T)$ occur at the same temperatures in all samples. Such a strong change in ϵ' values unaccompanied by notable changes in dielectric losses indicates that the addition of MoS₂ nanotubes either predominantly induces changes in the order of the PVDF structure or decreases the porosity of PVDF and at the same time does not implement any additional defects into the material structure itself. The latter was observed in SEM (see inset to Fig. 2) which revealed that the addition of MoS₂ NTs notably decreased the porosity of the film while vibrational spectroscopy showed no significant changes to the structure of PVDF.

On further addition of the nanotubes, the values of both ϵ' and ϵ'' slightly increase, which can be attributed to the increased electrical conductivity of the composite due to the

semiconducting [23] MoS₂ inclusions (as σ' and ε'' are directly related and influence ε' via Kramers-Kronig relations). This effect becomes even more evident in Fig. 7, which depicts the values of the real parts of the complex dielectric constant and ac electrical conductivity, detected in all three samples at 150 K, 293 K and 325 K.

Figure 8 shows the temperature-dependent dielectric response of HT PVDF–MoS₂ films. In this case the pure PVDF film reveals different dielectric behavior than the RT PVDF film (see Fig. 9), which can be attributed to the rich morphology of the PVDF itself [1, 38]. Both Raman spectroscopy and FTIR-ATR have confirmed the presence of α -, β - and γ -phases (see Figs. 3, 4 and 5). It is evident from Fig. 9 that upon addition of 1 wt% of MoS₂ NTs there is no notable increase or decrease in the values of ε' , ε'' , and σ' , which can be attributed to the superposition of two opposite effects. First, the presence of semiconducting MoS₂ NTs increases the values of ε' , ε'' , and σ' due to the Kramers-Kronig relations. Second, the increase of the non-polar α -phase content causes a decrease to the ε' , ε'' , and σ' [1, 8, 28]. Upon increasing to 2 wt% of MoS₂ NTs, the values of all, ε' , ε'' , and σ' only slightly increase, which can be attributed mostly to the addition of semiconducting MoS₂ nanotubes, since the α -phase content, detected by vibrational spectroscopy, has no significant increase.

Conclusions

Poly(vinylidene fluoride) [PVDF] composite films with 0, 1, and 2 wt% of MoS₂ nanotubes were prepared from solutions using the doctor blade method and dried at either room temperature or 110 °C. Vibrational spectroscopy has shown that films dried at room temperature are homogeneous and crystallize mainly in the γ -phase, regardless of the MoS₂ concentration. Dielectric spectroscopy results revealed a strong decrease in the value of the dielectric constant from $\varepsilon' \sim 7$ (pure PVDF) to $\varepsilon' \sim 4$ (PVDF with 1 wt% of MoS₂), which may be attributed to a decrease of porosity that was observed with SEM.

PVDF–MoS₂ films dried at 110 °C were heterogeneous and the α -phase content increased upon addition of 1 wt% MoS₂ nanotubes. Detailed analysis of FTIR-ATR and Raman spectroscopy results has shown that these films in fact consist of small areas containing individual α , β , or γ -phase and the top surface is richer in α -phase in comparison to the bottom surface of the film. In this case, high values of $\varepsilon' \sim 10$ have been detected in the pure PVDF film. Upon addition of 1 wt% MoS₂ no notable change in ε' , ε'' , and σ' values was detected and it may be assumed that this is a direct consequence of the superposition of two opposite effects: (i) the presence of semiconducting MoS₂ nanotubes, which increases the values of the dielectric constant, and (ii) the increasing

content of the non-polar α -phase in the PVDF, which decreases dielectric constant values. Upon further addition of MoS₂ a slight increase of in ε' , ε'' , and σ' values was detected, which can be attributed mostly to the addition of semiconducting MoS₂ nanotubes, since the α -phase content remained the same.

To summarize, we have shown that the dielectric response of PVDF–MoS₂ nanotubes composite films is a direct consequence of structural properties, revealed by FTIR-ATR, Raman spectroscopy, and SEM. It can thus be suggested that the dielectric properties of PVDF–MoS₂ nanotubes composites can be tailored by changing their preparation conditions.

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Compliance with ethical standards

Conflict of interest There is no conflict of interest.

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